



UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE
United States Patent and Trademark Office
Address: COMMISSIONER FOR PATENTS
P.O. Box 1450
Alexandria, Virginia 22313-1450
www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/696,525	10/29/2003	Chieng-Chung Chen	500-004	6390	
24002	7590	07/20/2006	EXAMINER		
ANTHONY R. BARKUME				PHAN, TRONG Q	
20 GATEWAY LANE				ART UNIT	
MANORVILLE, NY 11949				PAPER NUMBER	
				2827	

DATE MAILED: 07/20/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No.	Applicant(s)	
	10/696,525	CHEN, CHIENG-CHUNG	
	Examiner	Art Unit	
	TRONG PHAN	2827	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

1) Responsive to communication(s) filed on 29 June 2006.

2a) This action is FINAL. 2b) This action is non-final.

3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

4) Claim(s) 1-13 is/are pending in the application.
4a) Of the above claim(s) 3-5 and 11 is/are withdrawn from consideration.

5) Claim(s) _____ is/are allowed.

6) Claim(s) 1,2,6-10,12 and 13 is/are rejected.

7) Claim(s) _____ is/are objected to.

8) Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

9) The specification is objected to by the Examiner.

10) The drawing(s) filed on _____ is/are: a) accepted or b) objected to by the Examiner.

 Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).

 Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).

11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).

a) All b) Some * c) None of:

1. Certified copies of the priority documents have been received.
2. Certified copies of the priority documents have been received in Application No. _____.
3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

1) Notice of References Cited (PTO-892)
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)
Paper No(s)/Mail Date ____.

4) Interview Summary (PTO-413)
Paper No(s)/Mail Date. ____.
5) Notice of Informal Patent Application (PTO-152)
6) Other: ____.

DETAILED ACTION

Claim Rejections - 35 USC § 103

1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

2. Claims 1-2 and 9-10 are rejected under 35 U.S.C. 103(a) as being unpatentable over Applicant's Fig. 1 Prior Art, in view of Nakano, 6,147,923.

Regarding claims 1-2 and 9-10:

Applicant's Fig. 1 Prior Art discloses a memory pumping circuit comprising:
MOS capacitor 12;
current source 11;
node between current source 11 and MOS capacitor 12 providing a pumping voltage VPP as a voltage source for a word line;
driving circuit comprising inverter 13.

What is not shown in Applicant's Fig. 1 Prior Art is the storage capacitor as recited in claims 1-2 and 9-10.

Nakano, 6,147,923, discloses in Fig. 1 a voltage boosting circuit 10A for providing the boosted voltage VOUT to the word line of a memory device (see lines 13-15, column 1) including:
a pumping up circuit comprising an NMOS capacitor 13 and a PMOS capacitor 18 connected in series between the boosted voltage VOUT and the output VE of inverter

circuit 32. It should be noted that, in an initial state, middle point voltage control circuit 20 driving the middle point voltage VM to 0V, therefore, it has nothing to do with the pump up circuit, only end point voltage control inverter circuit 30 driving both NMOS capacitor 13 and PMOS capacitor 18 to the on-state to boost the VOUT up to VCC (see Fig. 2(A) and lines 37-56, column 4).

It would have been obvious under 35 USC 103(a) to one of ordinary skill in the art at the time of the invention was made to utilize the pumping up circuit comprising NMOS capacitor 13 connected in series with PMOS capacitor 18 in Fig. 1 of Nakano, 6,147,923, for the MOS capacitor 12 in Applicant' s Fig. 1 PriorArt for the purpose of providing faster boosting (see lines 5-6, column 2 of Nakano, 6,147,923).

Furthermore, MOS transistor 211 in Fig. 2(A) of the present invention having gate, drain and source commonly connected together, therefore, it is considered as a decoupling capacitor as well known in the art. Adding a decoupling capacitor into a prior art circuit is an insignificantly patentable feature since one of ordinary skill in the art would have known to add a decoupling capacitor in series with a capacitor for the purpose of enhancing the capacitance.

3. Claims 6-8 and 12-13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Applicant's Fig. 1 Prior Art, in view of Nakano, 6,147,923, and further in view of Hiratsuka et al., 5,453,707.

Regarding claims 6-8 and 12-13:

What is not shown in Applicant's Fig. 1 Prior Art, which is modified Nakano, 6,147,923, is the driving circuit consists of a PMOS transistor and a NMOS transistor

generating a first clock signal according to a second clock signal and a third clock signal as recited in claims 6-8 and 12-13.

Hiratsuka et al., 5,453,707, discloses in Fig. 4 the teaching of using CMOS inverter 18 consists of PMOS transistor Mp1 and NMOS transistor Mn1 to generate first clock signal 01 according to second clock signal at the output of NAND gate 12 and third clock signal at the output of NOR gate 13 having different phases with each other as shown in Fig. 5.

It would have been obvious under 35 USC 103(a) to one of ordinary skill in the art at the time of the invention was made to utilize the CMOS inverter 18 in Figs. 4-5 of Hiratsuka et al., 5,453,707, for the inverter I3 in Applicant's Fig. 1 Prior Art, which is modified by Nakano, 6,147,923, for the purpose of reducing power dissipation and preventing power source noise and ground noise (see lines 43-49, column 3 of Hiratsuka et al., 5,453,707).

Conclusion

4. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Keeth et al., 6,735,102 (see decoupling capacitor 44 in Fig. 3A and line 31, column 23).

5. Any inquiry concerning this communication or earlier communications from the examiner should be directed to TRONG PHAN whose telephone number is (571) 272-1794. The examiner can normally be reached on M-F (8:30-5:00).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, AMIR ZARABIAN can be reached on (571)272-1852. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

trong phan
TRONG PHAN
PRIMARY EXAMINER